

Switching diode

New**New**^{*1}

DAN217U / BAV99U^{*1} / DAN217

*1 BAV99U is only sold in countries other than Japan.

●Application

Ultra high speed switching

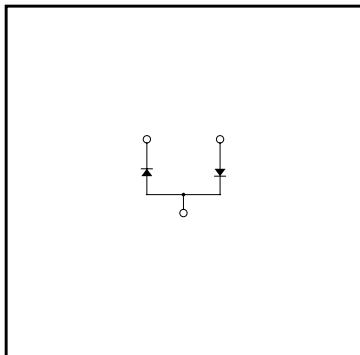
●Features

- 1) Small surface mounting type. (UMD3,SMD3)
- 2) Two diode elements are connected in series
(VF × 2) per circuit.

●Construction

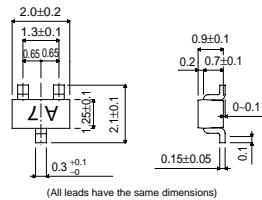
Silicon epitaxial planar

●Circuit



●External dimensions (Units : mm)

DAN217U / BAV99U



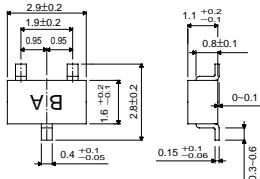
(All leads have the same dimensions)

ROHM : UMD3

EIAJ : SC-70

JEDEC : SOT-323

DAN217



(All leads have the same dimensions)

ROHM : SMD3

EIAJ : SC-59

JEDEC : SOT-346

●Absolute maximum ratings (Ta=25°C)

Type	Peak reverse voltage V _{RM} (V)	DC reverse voltage V _R (V)	Peak forward current I _{FM} (mA)	Mean rectifying current I _O (mA)	Surge current (1μs) I _{surge} (mA)	Power dissipation (TOTAL) P _d (mW)	Junction temperature T _j (°C)	Storage temperature T _{stg} (°C)
DAN217U	80	80	300	100	4000	200	150	-55 ~ +150
BAV99U	80	80	300	100	4000	200	150	-55 ~ +150
DAN217	80	80	300	100	4000	200	150	-55 ~ +150

DAN217U / BAV99U / DAN217

Diodes

●Electrical characteristics (Ta=25°C)

Type	Forward voltage		Reverse current		Fig
	V _F (V) Max.	Cond.	I _R (μA) Max.	Cond.	
		I _F (mA)		V _R (V)	
DAN217U	1.2	100	0.2	70	1 ~ 3
BAV99U	1.2	100	0.2	70	1 ~ 3
DAN217	1.2	100	0.1	70	4 ~ 6

●Electrical characteristic curves (Ta=25°C)

(DAN217U,BAV99U)…Fig.1~3

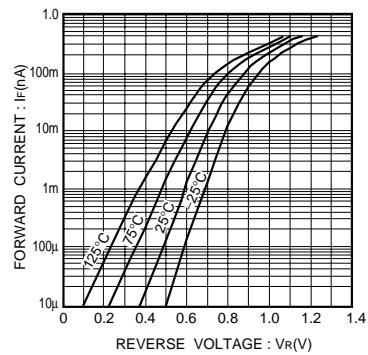


Fig.1 Forward characteristics

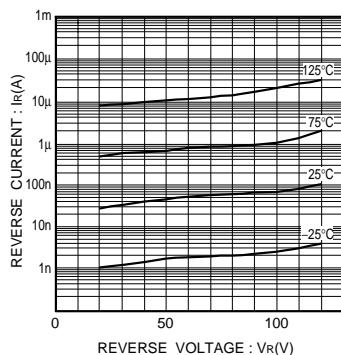


Fig.2 Reverse characteristics

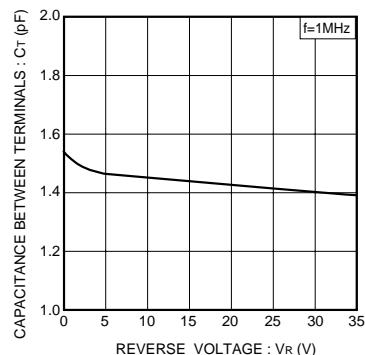


Fig.3 Capacitance between terminals characteristics

(DAN217) …Fig.4~6

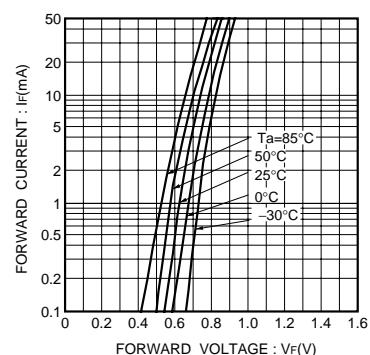


Fig.4 Forward characteristics

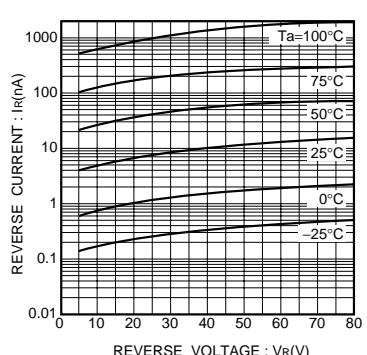


Fig.5 Reverse characteristics

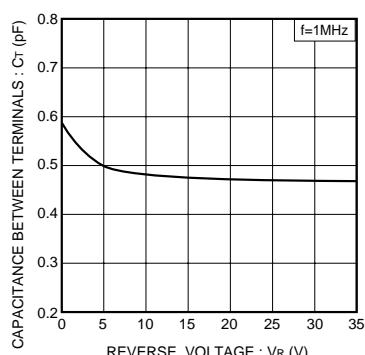


Fig.6 Capacitance between terminals characteristics